BT139B-600B

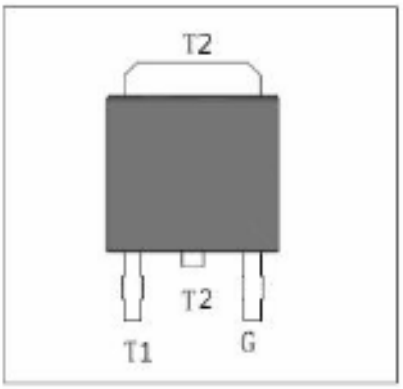
TRIACS

RoHS COMPLIANT

Features:

* NPNPN Bi-direction Triac
* Back multilayer metal electrode
* High temperature reliability
* Glass Passivated junction chips

TO-263



Application:

Power tool ,moto speed controller,
Vacuum cleaner,heating temperature controller, Solid state relay and phase control circuits.

Symbol	Absolute maximum ratings Parameters			Value	Unit
$I_{T(RMS)}$	RMS on-state current	Tc=90℃		16	A
I_{TSM}	Non repetitive surge peak on-state current	F=50HZ	t=20ms	160	A
I^2t	I^2t value for fusing	tp=10ms		144	A^2S
di/dt	Critical rate of rise of on-state current	Tj=125℃		50	A/us
V_{DRM}/V_{RRM}	Non repetitive surge peak off-state voltage	Tj=25℃		600	V
I_{GM}	Peak gate current	Tj=125℃		4	A
$P_{G(AV)}$	Average gate power dissipation		Tj=125℃	1	W
Tstg	Storage junction temperature range			-40℃~+150℃	℃
Tj	Operating junction temperature range(150℃ only suitable for B and C type)			—40℃+125℃	℃

Electrical Characteristics(4 quadrant) (Tj=25℃, unless otherwise specified)

Symbol	Test Condition	Quadrant		Value	Unit
I_{GT}	V_D=12V R_L=100Ω	I II III IV	MAX	70	mA
V_{GT}			MAX	1.5	V
V_{GD}	Tj=125℃		MIN	0.2	V
I_H	I_T=0.5A		MAX	60	mA
I_L	I_G=1.2I_{GT}		MAX	60	mA
				100	
dv/dt	V_D=2/3V_{DRM} Tj=125℃		MIN	500	V/us
(dv/dt)c	Tj=125℃		MIN	10	V/us

Static Characteristics

Symbol	Test Condition			Value	Unit
V_{TM}	I_{TM}=32A	Tj=25℃	MAX	1.5	V
V_{T0}	Threshold voltage	Tj=125℃	MAX	0.87	V
Rd	Dynamic resistance	Tj=125℃	MAX	14.6	mΩ
I_{DRM} I_{RRM}	V_{DRM} = V_{DRM}	Tj=25℃ Tj=125℃	MAX	5	uA
				1	mA
$R_{th(j-c)}$	Junction to case (AC)	. 2.1 .			℃/W

● TO-263 Dimensions